



SBR12U45LH1

#### 12A SBR<sup>®</sup> SUPER BARRIER RECTIFIER POWERDI<sup>®</sup>5SP-B

## **Product Summary**

V <sub>RRM</sub> (V)	I <sub>O</sub> (A)	V <sub>F(typ)</sub> @ +125°C (V)	I <sub>R(MAX)</sub> @ V <sub>RRM</sub> (mA)
45	12	0.38	0.3

## Description

The SBR12U45LH1 uses SBR patented technology that offers ultralow V<sub>F</sub> to reduce forward power loss and improve efficiency. Encapsulated in the new PDI-5SP package with a 0.75mm low height profile and protruding leads for easy soldering, it is especially suited for use as a bypass diode in solar panels.

## Applications

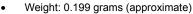
Solar Bypass Diode

### **Features**

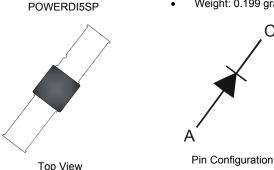
- Designed as bypass diodes for solar panels •
- Low profile height (0.75mm) and 7.6mm protruding leads, enabling the package to be integrated within the solar glass panel
- Selectively rated for +200°C maximum junction temperature for high thermal reliability and excellent high temperature stability
- Patented Super Barrier Rectifier technology
- Ultra low forward voltage drop to minimize forward power losses
- Very low reverse leakage to ensures maximum efficiency of solar panel
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2) •
- Halogen and Antimony Free. "Green" Device (Note 3)

## Mechanical Data

- Case: POWERDI5SP-B
- Case Material: Molded Plastic, UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Polarity: Cathode bar mark on top and cathode notch on lead



С



### Ordering Information (Note 4)

Part Number	Case	Packaging
SBR12U45LH1-13	POWERDI5SP-B	3000 / Tape & Reel

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied. 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**



12U45LH1 = Product Type Marking Code Dil = Manufacturers' Code Marking YYWWK = Date Code Marking YY = Last Two Digits of Year (ex: 14 for 2014) WW = Week Code  $(01 \sim 53)$ K = Factory Designator

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Notes:



#### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>RM</sub>	45	V
Average Rectified Output Current	lo	12	A
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I <sub>FSM</sub>	300	А

### **Thermal Characteristics**

Characteristic		Symbol	Value	Unit	
Typical Thermal Resistance Junction to Ambient (Note 5)		R <sub>0JA</sub>	66	°C/W	
	V <sub>R</sub> ≤ 80% V <sub>RRM</sub>		-65 to +150		
Operating Temperature Range	DC Forward Mode (Note 7)	TJ	≤ 175	°C	
	DC Forward Mode (Note 8)		≤ 200		
Storage Temperature Range		T <sub>STG</sub>	-65 to +175	°C	

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
	V <sub>F</sub>		0.40	0.48	V	I <sub>F</sub> = 10A, T <sub>J</sub> = +25°C
Forward Voltage Drop		—	0.42	0.50		I <sub>F</sub> = 12A, T <sub>J</sub> = +25°C
		_	0.38	0.45		I <sub>F</sub> = 12A, T <sub>J</sub> = +125°C
	I <sub>R</sub>	_	70	200	u Au	V <sub>R</sub> = 40V, T <sub>J</sub> = +25°C
Lookago Current (Note 6)		_	90	300		V <sub>R</sub> = 45V, T <sub>J</sub> = +25°C
Leakage Current (Note 6)		_	19	_	mA	V <sub>R</sub> = 45V, T <sub>J</sub> = +125°C
		_	60	_		V <sub>R</sub> = 45V, T <sub>J</sub> = +150°C

5. FR-4 PCB, 2oz. Copper, minimum recommended pad layout per http://www.diodes.com.pdf.
6. Short duration pulse test used to minimize self-heating effect.
7. Max junction temperature +175°C guaranteed for 2 hours at maximum output.
8. Max junction temperature +200°C guaranteed for 2 hours at maximum output. Notes:





= 85°C

 $T_A = 25^{\circ}C$ 

400

500

f = 1MHz

600

 $T_{\Delta} = -55^{\circ}C$ 

300

Figure 2 Typical Forward Characteristics

T<sub>A</sub> = 150°C

100

5

10

9

15

20

V<sub>R</sub>, REVERSE VOLTAGE (V)

Figure 4 Typical Junction Capacitance

25

13.5 18 22.5 27 31.5 36 40.5 45

V<sub>R</sub>, DC REVERSE VOLTAGE (V)

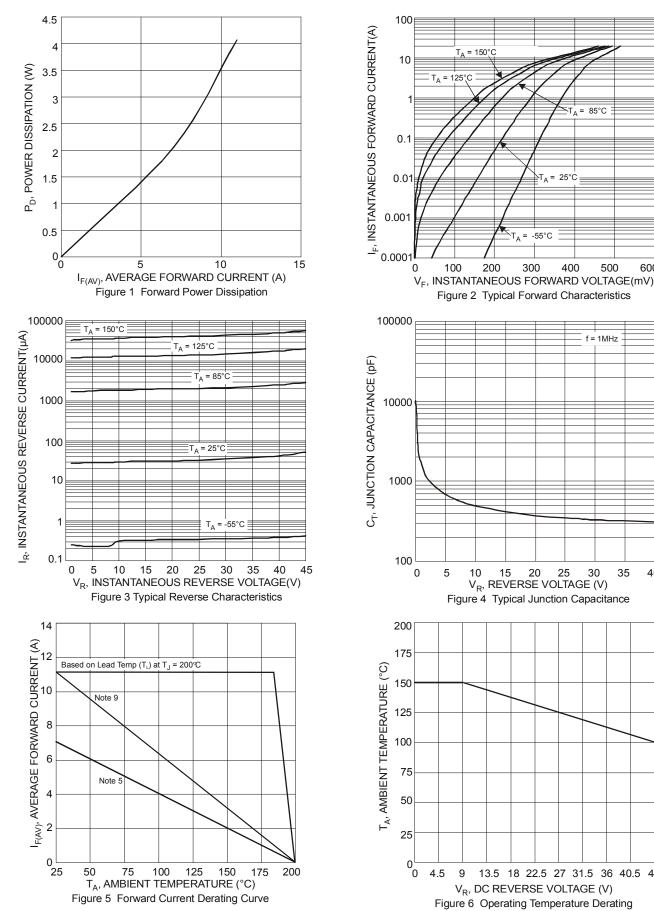
Figure 6 Operating Temperature Derating

30

35

40

200

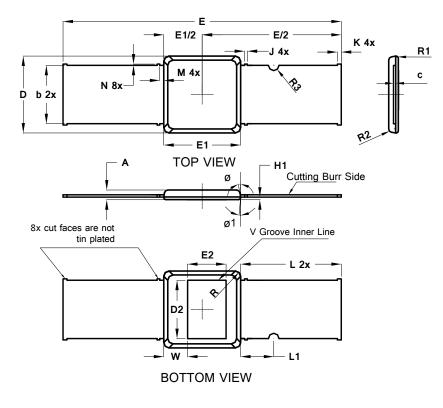


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# **Package Outline Dimensions**

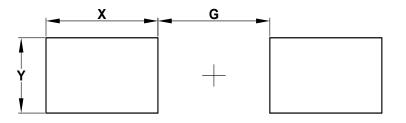
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



Type B Dim Min Max Typ							
A	IVIIII	0.75	Тур				
B	4.30	4.50	4.40				
C	0.155	0.191	4.40				
D	5.70	5.90	5.80				
		5.90	5.80				
D2	4.40	—	_				
E	20.8	21.2	21.0				
E1	5.70	5.90	5.80				
E2	<b>E2</b> 2.90		—				
H1	0.19	0.21	0.20				
J	_	_	0.20				
κ	_	_	0.30				
L	L —		7.60				
L1	L1 —		2.50				
М	_	_	0.30				
Ν	0	0.20	_				
R	_	_	0.40				
R1	_	_	0.15				
R2		_	0.25				
R3	I		0.40				
W	1.63	1.97	1.80				
Ø	8°	12°	_				
Ø 1	3°	7°	_				
All Dimensions in mm							

# Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)			
G	8.101			
Х	8.100			
Y	5.100			



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